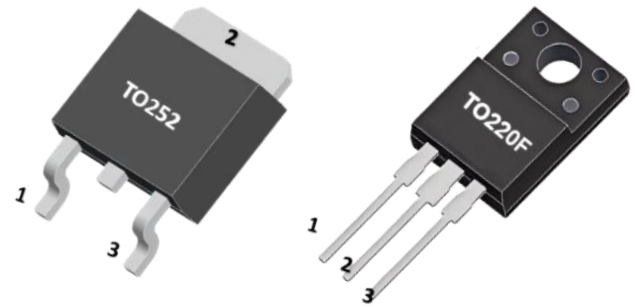


## DESCRIPTION

The WTM20N06VD/F is an N-channel enhancement mode power MOSFET using our advanced technology to provide customers with a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode. The WTM20N06VD/F is universally applied in low voltage, such as automotive, high efficiency switching for DC/DC converters and DC motor control. The WTM20N06VD/F meet the ROHS and Green Product requirement with full function reliability approved.



## FEATURE

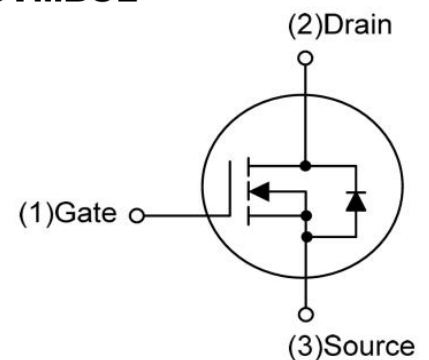
- \* Excellent package for good heat dissipation.
- \* Ultra low gate charge.
- \* Low reverse transfer capacitance.
- \* Fast switching capability.
- \* Avalanche energy specified.

## MARKING



WPM : LOGO  
20N06VD=Device Code (TO-252)  
20N06VF =Device Code (TO-220F)  
XXX YYWW=Date Code

## SYMBOL



## ABSOLUTE MAXIMUM RATINGS( $T_A=25^{\circ}\text{C}$ , unless otherwise specified.)

| SYMBOL                        | PARAMETER                                            |         | VALUE    | UNIT                 |
|-------------------------------|------------------------------------------------------|---------|----------|----------------------|
| <b>VDSS</b>                   | Drain-Source Voltage                                 |         | 60       | V                    |
| <b>VGSS</b>                   | Gate Source Voltage                                  |         | $\pm 20$ | V                    |
| <b>ID</b>                     | Continuous Drain Current (Note 1)                    |         | 20       | A                    |
| <b>IDM</b>                    | Pulsed Drain Current (Note 2)                        |         | 80       | A                    |
| <b>EAS</b>                    | Single Pulsed Avalanche Energy (Note 3)              |         | 49       | mJ                   |
| <b>PD</b>                     | Maximum Power Dissipation (Note 1)                   | TO-220F | 30       | W                    |
|                               |                                                      | TO-252  | 40       |                      |
| <b>TJ</b>                     | Storage Temperature                                  |         | 150      | $^{\circ}\text{C}$   |
| <b>TSTG</b>                   | Thermal Resistance From Junction To Ambient          |         | -55~150  | $^{\circ}\text{C}$   |
| <b>R<math>\theta</math>JA</b> | Thermal Resistance from Junction to Ambient (Note 6) | TO-220F | 62.5     | $^{\circ}\text{C/W}$ |
|                               |                                                      | TO-252  | 100      |                      |
| <b>R<math>\theta</math>Jc</b> | Thermal Resistance From Junction To Case (Note 1)    | TO-220F | 5        | $^{\circ}\text{C/W}$ |
|                               |                                                      | TO-252  | 3.12     |                      |

Notes: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

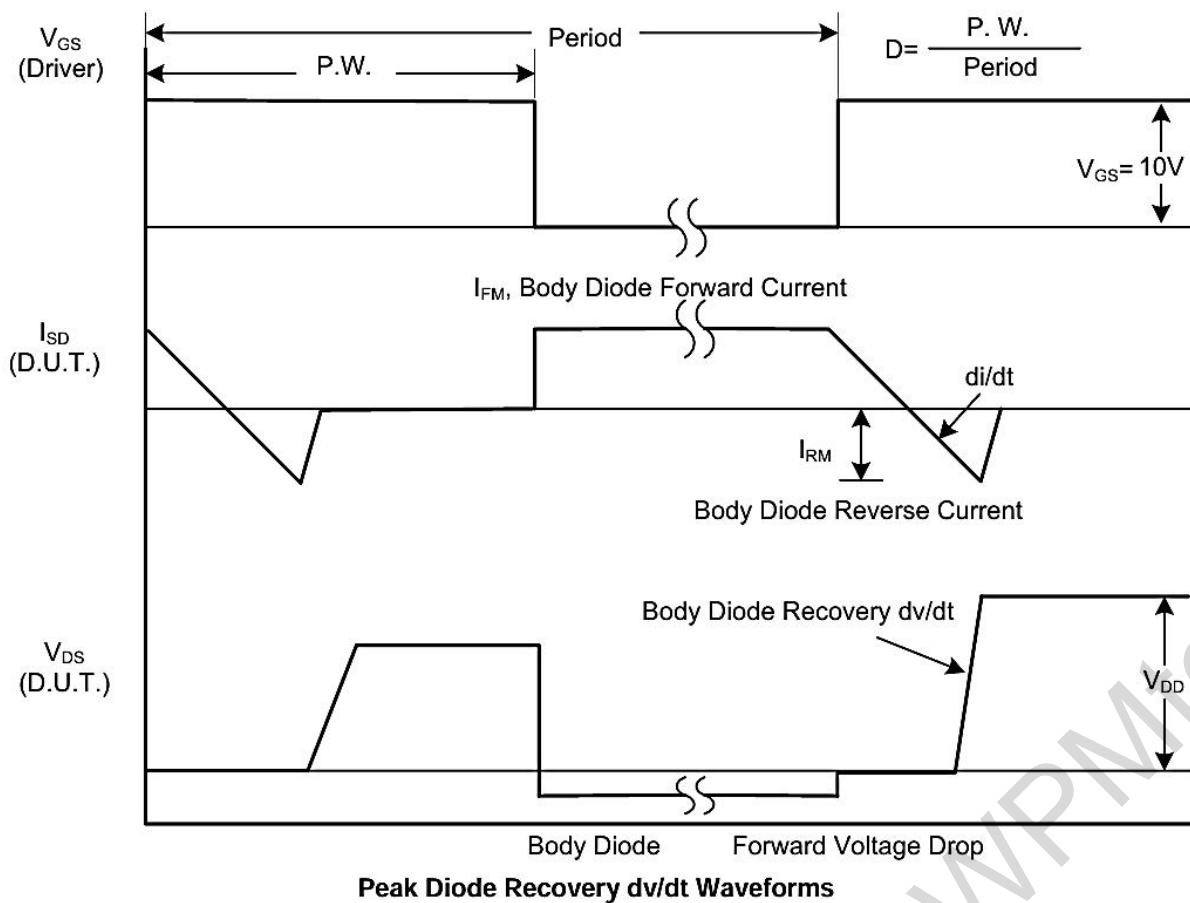
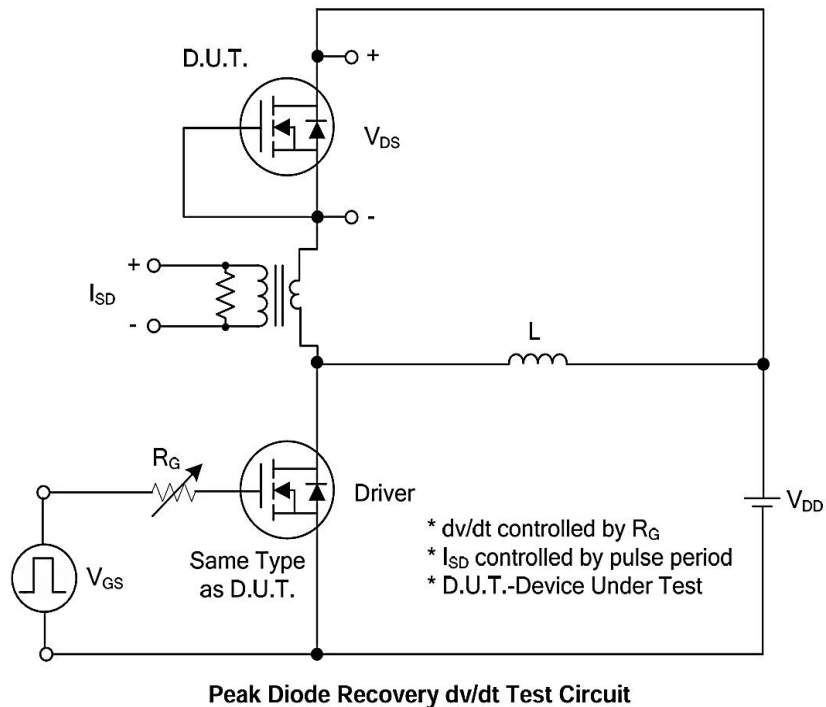
## ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                                              | SYMBOL   | TEST CONDITIONS                    | MIN | TYP | MAX  | UNIT |
|--------------------------------------------------------|----------|------------------------------------|-----|-----|------|------|
| OFF CHARACTERISTICS                                    |          |                                    |     |     |      |      |
| Drain-Source Breakdown Voltage                         | V(BR)DSS | VGS=0V, ID=250μA                   | 60  |     |      | V    |
| Zero gate voltage drain current                        | IDSS     | VDS=60V, VGS=0V                    |     |     | 1    | μA   |
|                                                        |          | VDS=48V, VGS=0V, TJ=125°C          |     |     | 10   | μA   |
| Gate-body leakage current                              | IGSS     | VGS=±20V, VDS=0V                   |     |     | ±100 | nA   |
| ON CHARACTERISTICS (Note 4)                            |          |                                    |     |     |      |      |
| Drain-source on-state resistance                       | RDS(ON)  | VGS=10V, ID=10A                    |     | 26  | 35   | mΩ   |
|                                                        |          | VGS=4.5V, ID=10A                   |     | 35  | 50   |      |
| Gate Threshold Voltage                                 | VGS(TH)  | VGS=VDS, ID=250μA                  | 1.0 | 1.7 | 2.5  | V    |
| DYNAMIC PARAMETERS (Note 4,5)                          |          |                                    |     |     |      |      |
| Input Capacitance                                      | Ciss     | VGS=0V, VDS=25V<br>f=1.0MHz        |     | 850 | 1700 | pF   |
| Output Capacitance                                     | Coss     |                                    |     | 60  | 120  |      |
| Reverse Transfer Capacitance                           | Crss     |                                    |     | 55  | 110  |      |
| Gate resistance                                        | Rg       | f =1MHz                            |     | 2.0 |      | Ω    |
| SWITCHING PARAMETERS(Note 4,5)                         |          |                                    |     |     |      |      |
| Total gate charge                                      | Qg       | VDS=30V, VGS=10V<br>ID=10A         |     | 18  | 36   | nC   |
| Gate-source charge                                     | Qgs      |                                    |     | 2.0 | 4    |      |
| Gate-drain charge                                      | Qgd      |                                    |     | 4.4 | 8.8  |      |
| Turn-On Delay Time                                     | td(on)   | VDS=30V, RL=2.5Ω<br>VGS=10V, RG=3Ω |     | 4.2 |      | nS   |
| Turn-On Rise time                                      | tr       |                                    |     | 3.4 |      |      |
| Turn-Off Delay Time                                    | td(off)  |                                    |     | 16  |      |      |
| Turn-Off Fall time                                     | tf       |                                    |     | 2   |      |      |
| DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS |          |                                    |     |     |      |      |
| Continuous drain-source diode forward current(Note1)   | IS       |                                    |     |     | 20   | A    |
| Pulsed drain-source diode forward current(Note 2)      | ISM      |                                    |     |     | 80   | A    |
| Drain-source diode forward voltage(Note 4)             | VSD      | IS=10A, VGS=0V                     |     |     | 1.2  | V    |

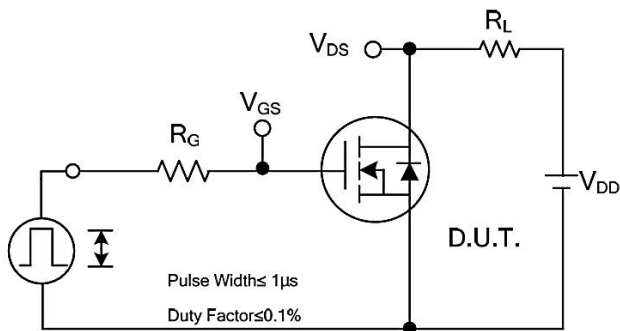
### Notes:

1.  $T_C=25^\circ\text{C}$  Limited only by maximum temperature allowed.
2.  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$ .
3. EAS condition:  $V_{DD}=30V, V_{GS}=10V, L=0.5mH, R_g=25\Omega$  Starting  $T_J = 25^\circ\text{C}$ .
4. Pulse Test : Pulse Width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$ .
5. Guaranteed by design, not subject to production.
6. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with  $T_a=25^\circ\text{C}$ .

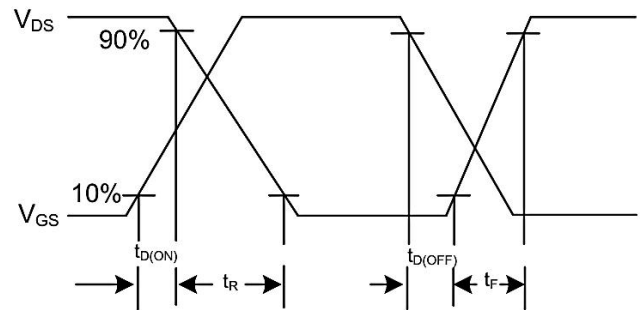
## TEST CIRCUITS AND WAVEFORMS(1)



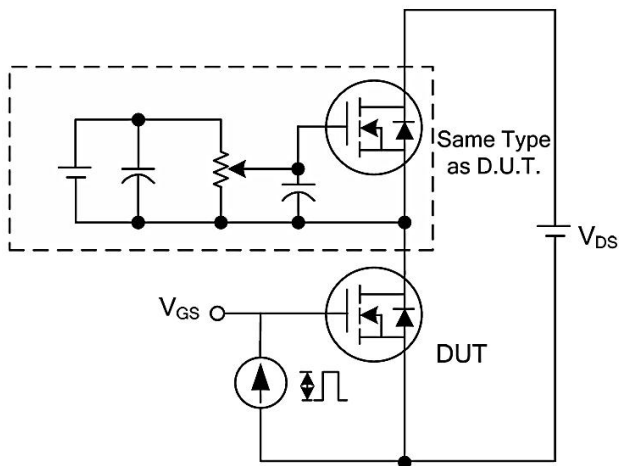
## TEST CIRCUITS AND WAVEFORMS(2)



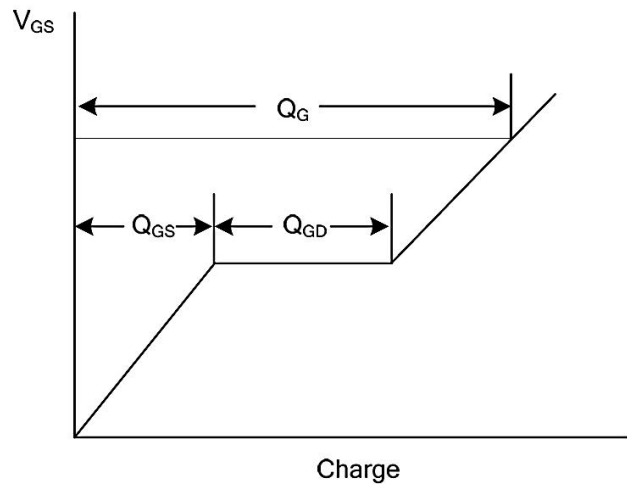
Switching Test Circuit



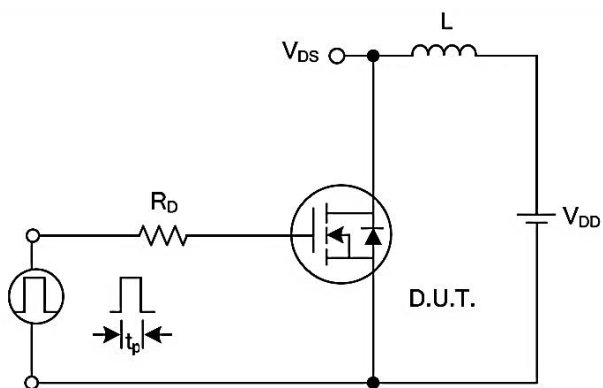
Switching Waveforms



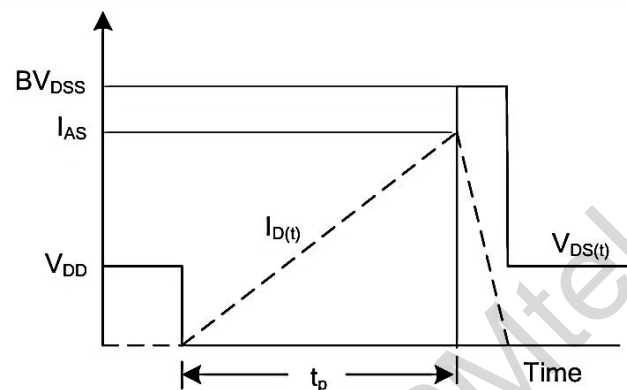
Gate Charge Test Circuit



Gate Charge Waveform

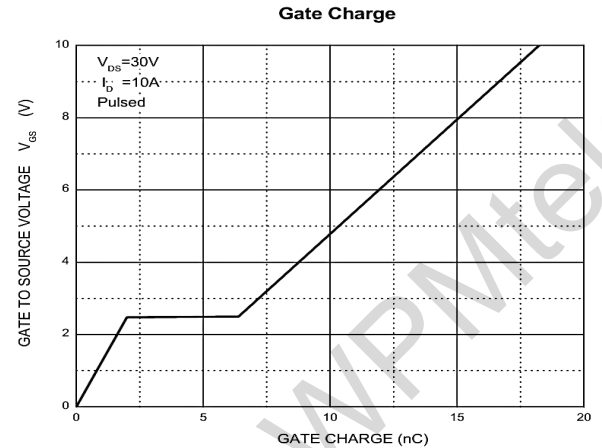
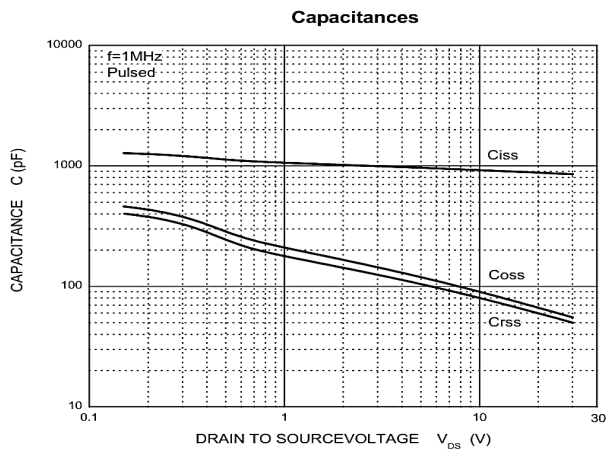
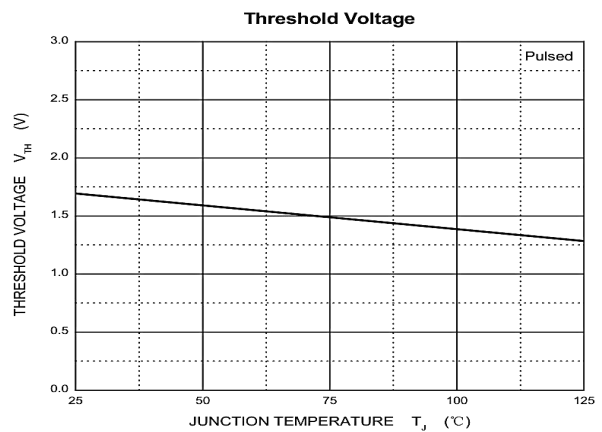
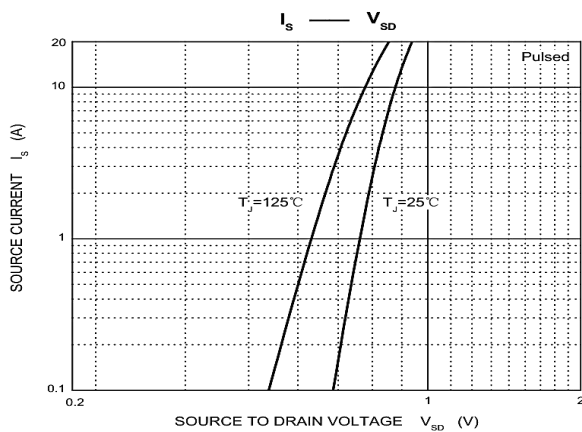
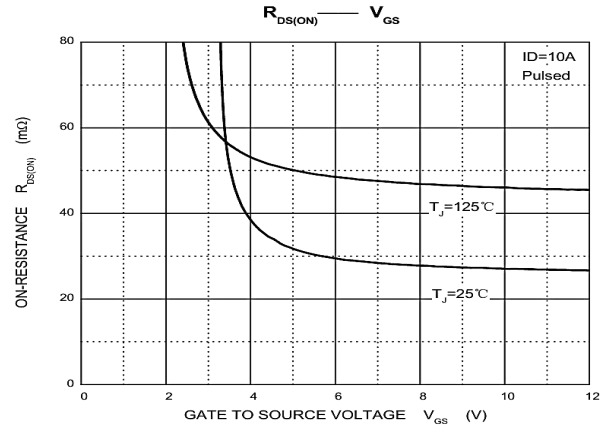
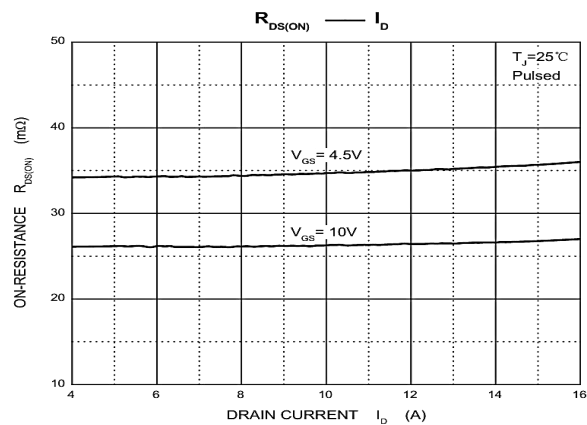
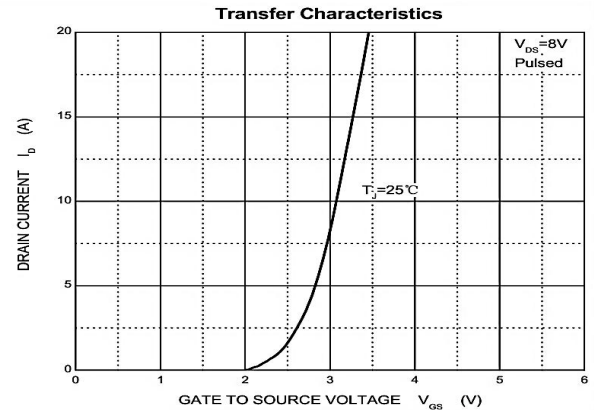
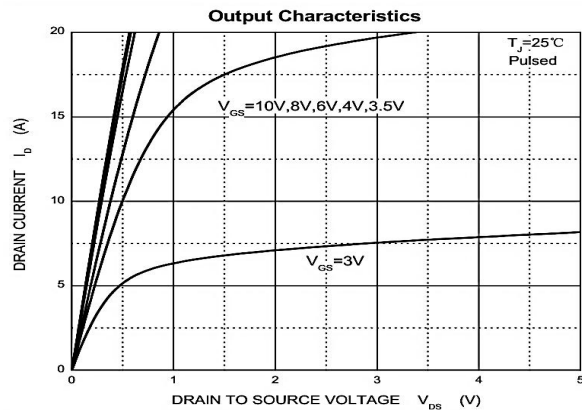


Unclamped Inductive Switching Test Circuit

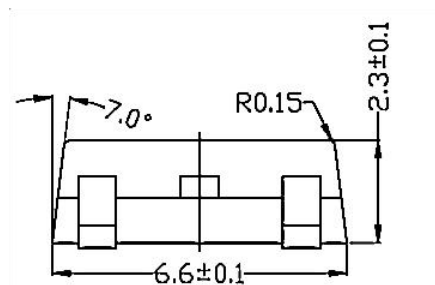
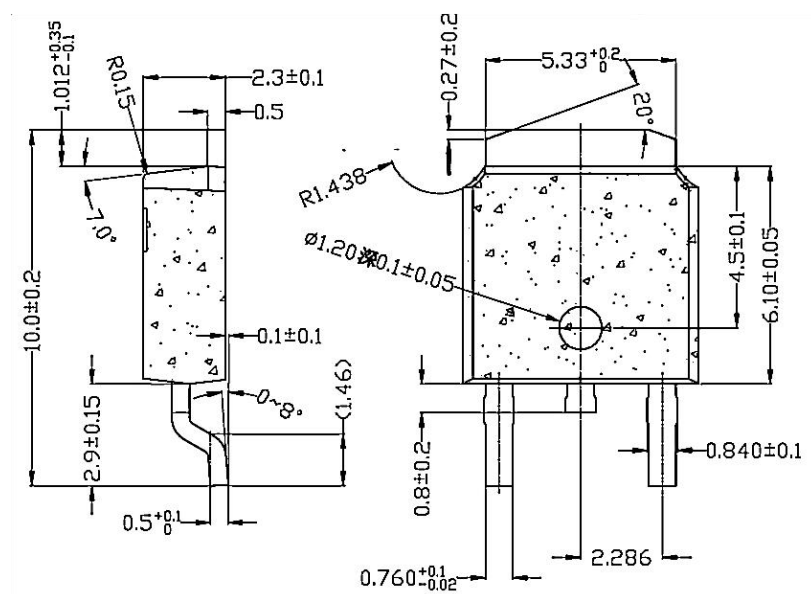


Unclamped Inductive Switching Waveforms

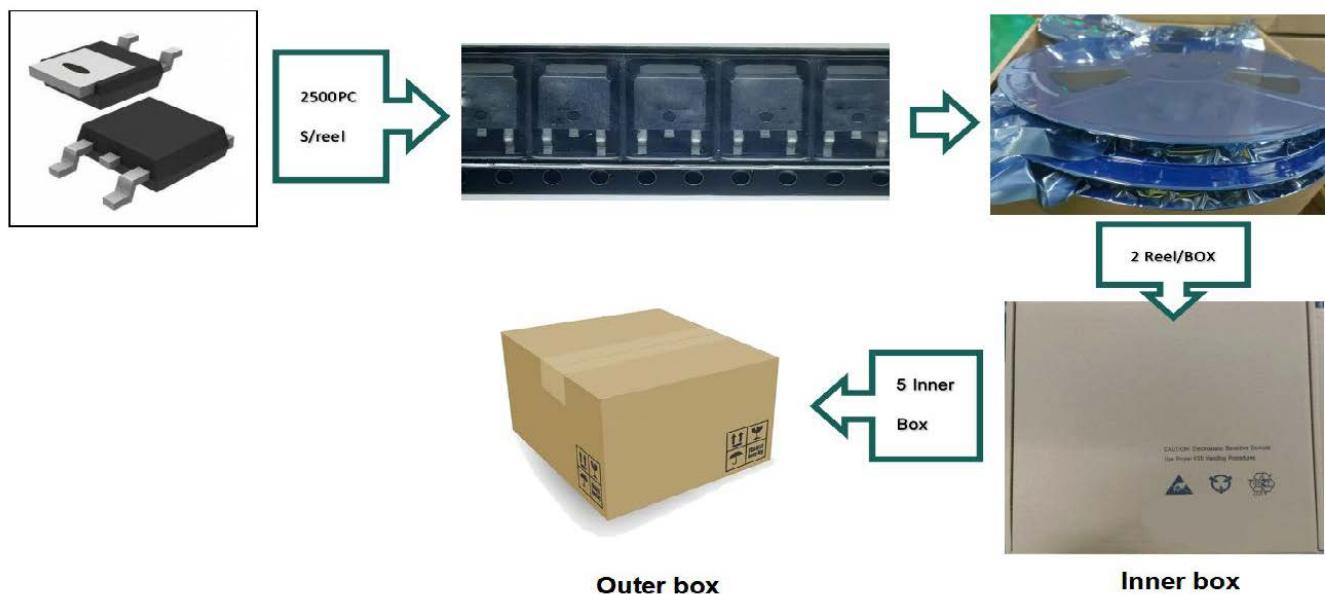
## TYPICAL CHARACTERISTICS



## TO - 252 PACKAGE OUTLINE DIMENSIONS

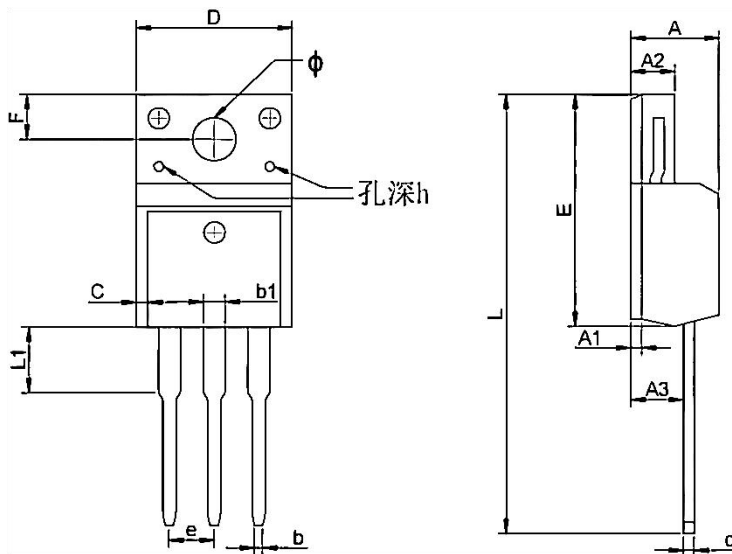


## TO - 252 PACKING INFORMATION



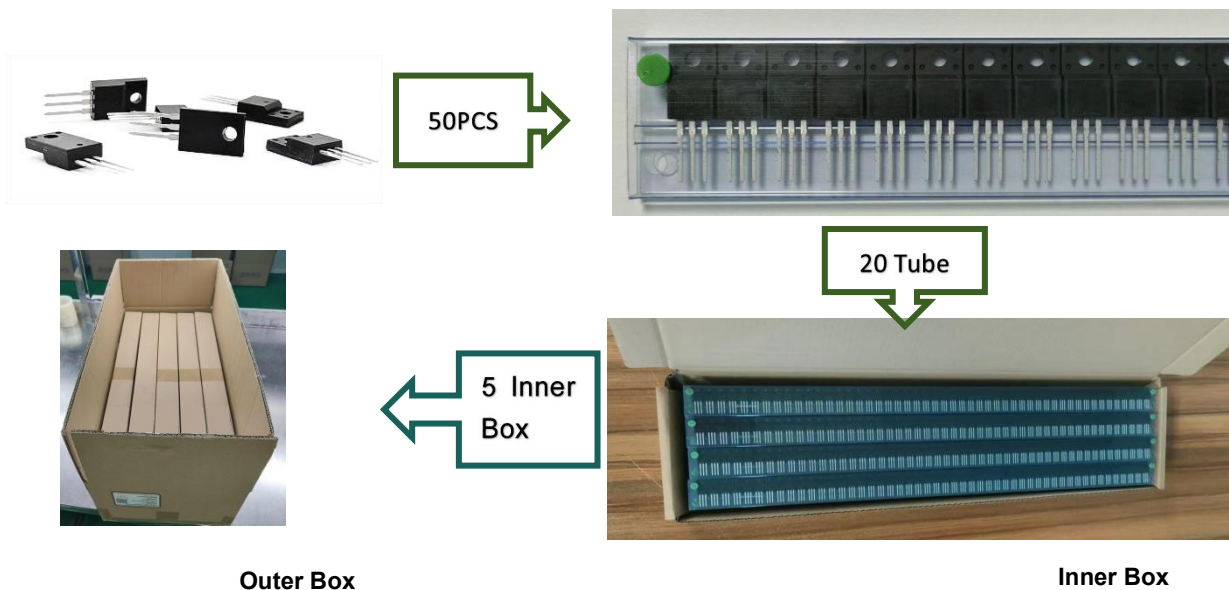
| Package version | Reel dimensions<br>$\Phi \times H$ (mm) | Per Reel (pcs) | Reels per box | Inner box dimensions<br>$L \times W \times H$ (mm) | Outer box (pcs) | Outer box dimensions<br>$L \times W \times H$ (mm) |
|-----------------|-----------------------------------------|----------------|---------------|----------------------------------------------------|-----------------|----------------------------------------------------|
| T0-252          | $\Phi 330 \times 20$                    | 2500           | 2             | 360*340*50                                         | 25000           | 375*375*280                                        |

## TO- 220F PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max    | Min                  | Max   |
| A      | 4.300                     | 4.750  | 0.169                | 0.185 |
| A1     | 1.830 REF                 |        | 0.072 REF            |       |
| A2     | 2.300                     | 2.850  | 0.090                | 0.112 |
| A3     | 2.500                     | 2.900  | 0.098                | 0.114 |
| b      | 0.400                     | 0.420  | 0.016                | 0.016 |
| b1     | 1.220                     | 1.280  | 0.048                | 0.050 |
| C      | 0.690                     | 0.720  | 0.027                | 0.028 |
| c      | 0.490                     | 0.510  | 0.019                | 0.020 |
| D      | 9.960                     | 10.200 | 0.392                | 0.400 |
| E      | 15.000                    | 15.950 | 0.588                | 0.625 |
| e      | 2.574 TYP                 |        | 0.101TYP             |       |
| F      | 3.470 REF                 |        | 0.136 REF            |       |
| y      | 3.200 REF                 |        | 0.125 REF            |       |
| h      | 0.000                     | 0.300  | 0.000                | 0.012 |
| L      | 28.780                    | 28.900 | 1.128                | 1.133 |
| L1     | 2.990                     | 3.100  | 0.117                | 0.122 |

## TO - 220F PACKING INFORMATION



| Package version | Tube dimensions<br>LxW×H<br>(mm) | Per Tube<br>(pcs) | Tube per box | Inner box dimensions<br>LxW×H<br>(mm) | PCS/<br>Inner box | Outer box dimensions<br>L×W×H(mm) | PCS/<br>Outer box |
|-----------------|----------------------------------|-------------------|--------------|---------------------------------------|-------------------|-----------------------------------|-------------------|
| TO-220F         | 530*32*7                         | 50                | 20           | 580*155*50                            | 1000              | 602*277*188                       | 5000              |

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